

NPN General Purpose Transistor

SSTA06 / MMSTA06 / MPSA06

●Features

- 1) V_{CE0} minimum is 80V. ($I_c=1mA$)
- 2) Complements the SSTA56 / MMSTA56 / MPSA56.

●Package, marking and packaging specifications

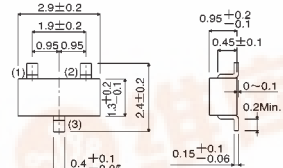
Part No.	SSTA06	MMSTA06	MPSA06
Packaging type	SST3	SMT3	TO-92
Mark	R1G	R1G	—
Code	T116	T146	T93
Basic order increment (pieces)	3000	3000	3000

●Absolute maximum ratings ($T_a=25^{\circ}C$)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CB0}	80	V
Collector-emitter voltage	V_{CE0}	80	V
Emitter-base voltage	V_{EB0}	4	V
Collector current	I_c	0.5	A
Collector power dissipation	SSTA06, MMSTA06	0.2	W
	MPSA06	0.625	
Junction temperature	T_j	150	$^{\circ}C$
Storage temperature	T_{stg}	-55~+150	$^{\circ}C$

●External dimensions (Units : mm)

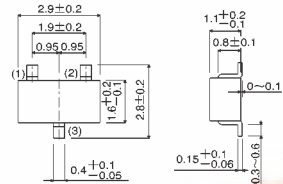
SSTA06



All terminals have same dimensions

ROHM : SST3

MMSTA06

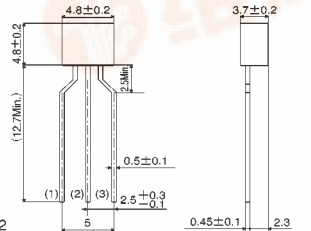


All terminals have same dimensions

ROHM : SMT3

EIAJ : SC-59

MPSA06



ROHM : TO-92

EIAJ : SC-43

●Electrical characteristics ($T_a=25^{\circ}C$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CB0}	4	—	—	V	$I_c=100\mu A$
Collector-emitter breakdown voltage	BV_{CE0}	80	—	—	V	$I_c=1mA$
Collector cutoff current	I_{cB0}	—	—	0.1	μA	$V_{CB}=80V$
	I_{cE0}	—	—	1		$V_{CE}=60V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	—	0.25	V	$I_c/I_E=100mA/10mA$
Base-emitter saturation voltage	$V_{BE(ON)}$	—	—	1.2	V	$V_{CE}/I_E=1V/100mA$
DC current transfer ratio	h_{FE}	100	—	—	—	$V_{CE}=1V, I_c=10mA$
		100	—	—		$V_{CE}=1V, I_c=100mA$
Transition frequency	f_t	100	—	—	MHz	$V_{CE}=2V, I_E=-10mA, f=100MHz$



● Electrical characteristic curves

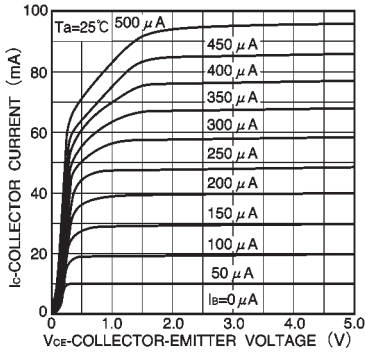


Fig.1 Grounded emitter output characteristics

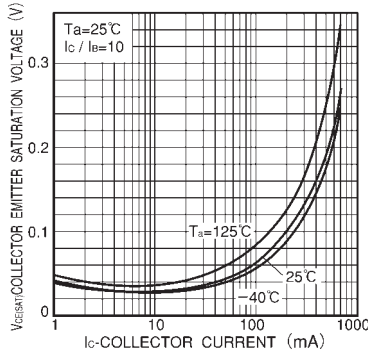


Fig.2 Collector-emitter saturation voltage vs. collector current

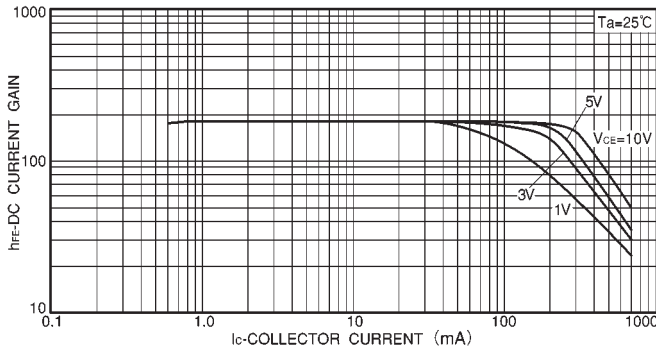


Fig.3 DC current gain vs. collector current (I)

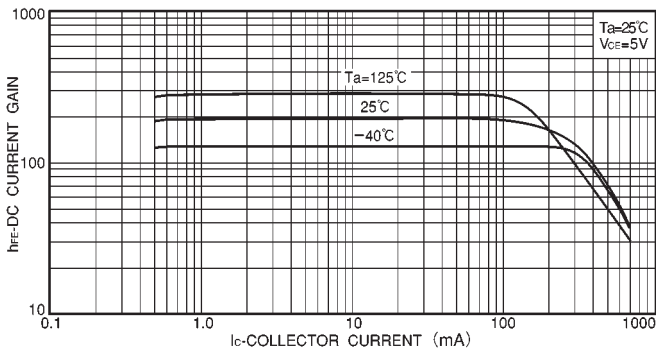


Fig.4 DC current gain vs. collector current (II)

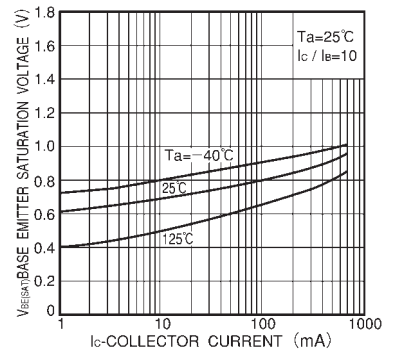


Fig.5 Base-emitter saturation voltage vs. collector current

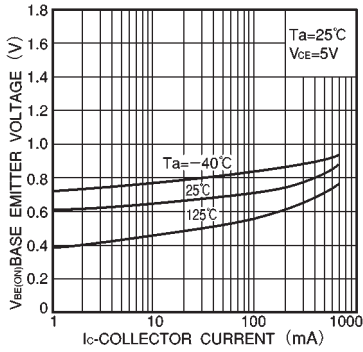


Fig.6 Grounded emitter propagation characteristics

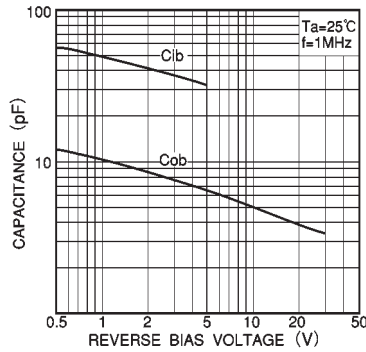


Fig.7 Input / output capacitance vs. voltage

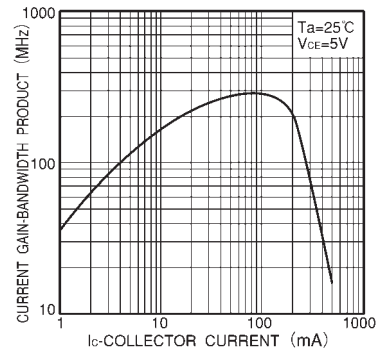


Fig.8 Gain bandwidth product vs. collector current